

D1029UK

ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA

(4 pls) DR

PIN 1 SOURCE (COMMON) PIN₂ DRAIN 1 PIN₃ DRAIN 2 PIN 4 GATE 2 PIN 5 GATE 1

DIM	Millimetres	Tol.	Inches	Tol.
Α	19.05	0.50	0.75	0.020
В	10.77	0.13	0.424	0.005
С	45°	5°	45°	5°
D	9.78	0.13	0.385	0.005
Е	5.71	0.13	0.225	0.005
F	27.94	0.13	1.100	0.005
G	1.52R	0.13	0.060R	0.005
Н	10.16	0.13	0.400	0.005
- 1	22.22	MAX	0.875	MAX
J	0.13	0.02	0.005	0.001
K	2.72	0.13	0.107	0.005
М	1.70	0.13	0.067	0.005
N	5.08	0.50	0.200	0.020
0	34.03	0.13	1.340	0.005
Р	1.61R	0.08	0.064R	0.003

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 350W - 28V - 175MHz**PUSH-PULL**

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 13 dB MINIMUM

APPLICATIONS

 VHF/UHF COMMUNICATIONS from 1 MHz to 200 MHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

	25.22	
$\overline{P_D}$	Power Dissipation	438W
BV_{DSS}	Drain – Source Breakdown Voltage *	70V
BV_{GSS}	Gate – Source Breakdown Voltage *	±20V
I _{D(sat)}	Drain Current *	35A
T _{stg}	Storage Temperature	–65 to 150°C
T _j	Maximum Operating Junction Temperature	200°C

^{*} Per Side

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
	PER SIDE						
BV _{DSS}	Drain-Source Breakdown	V _{GS} = 0	I _D = 100mA	70			\ \
	Voltage	v _{GS} = 0		70			V
ı	Zero Gate Voltage	\/ _ 29\/	V _{GS} = 0			7	mΛ
DSS	Drain Current	V _{DS} = 28V				,	mA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS} = 0			7	μΑ
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 7A	5.6			S
	TOTAL DEVICE						
G _{PS}	Common Source Power Gain	P _O = 350W		13			dB
η	Drain Efficiency	$V_{DS} = 28V$	I _{DQ} = 2A	65			%
VSWR	Load Mismatch Tolerance	f = 175MHz		20:1			_
PER SIDE							
C _{iss}	Input Capacitance	$V_{DS} = 28V$ V	$t_{GS} = -5V f = 1MHz$			420	pF
C _{oss}	Output Capacitance	$V_{DS} = 28V$ V	$f'_{GS} = 0$ $f = 1MHz$			210	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 28V V$	$t_{GS} = 0$ $f = 1MHz$			17.5	pF

^{*} Pulse Test: Pulse Duration = 300 μs , Duty Cycle \leq 2%

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 0.4°C / W
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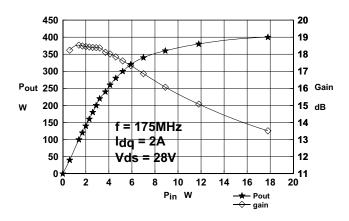
E-mail: sales@semelab.co.uk

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

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450 90 80 400 350 70 60 300 Pout 250 50 Drain Efficiency f = 175MHz200 40 ldq = 2A 150 30 Vds = 28V 20 100 50 10 2 14 16 18 ★ Pout → Drain Efficiency 6 12 Pin W

Figure 1Output Power and Gain vs. Input Power

Figure 2Output Power and Efficiency vs. Input Power

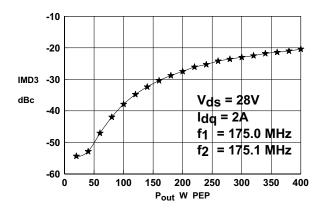


Figure 3 IMD3 vs. Output Power

OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency	Z _S	Z_{L}	
MHz	Ω	Ω	
175	2.1 + j1.9	2.8 + j2.4	
225	1.8 - j0.5	2.9 + j0.7	

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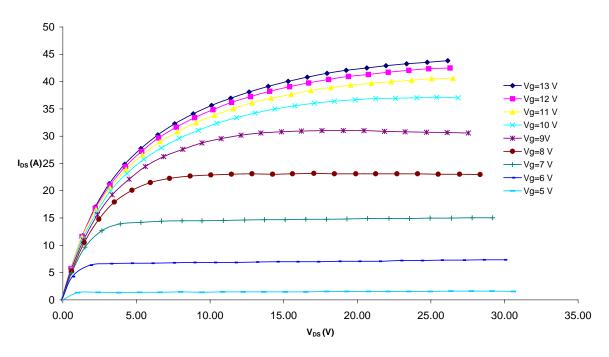


Figure 4 – Typical IV Characteristics.

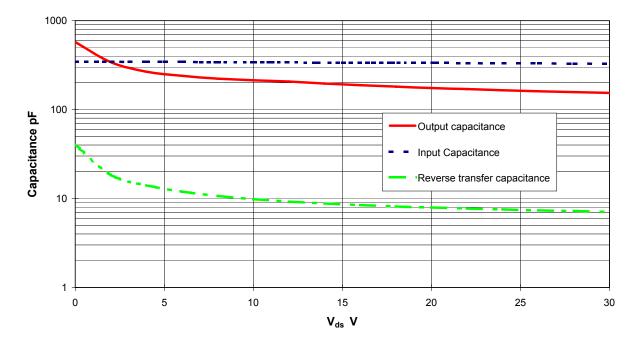


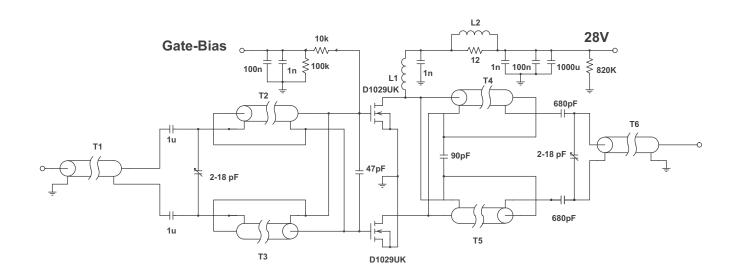
Figure 5 - Typical CV Characteristics.

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175MHz Test Fixture

T1, 2, 3,	7cm Storm Products EXE18 19/30 S1TW coaxial cable on Siemens
	B62152A1X1 2 hole core
T4,5	14cm Storm Products EXE18 19/30 S1TW coaxial cable
T6	11cm Storm Products EXE18 19/30 S1TW coaxial cable

L1 6 turns 1.2mm dia wire, 5mm internal diameter

L2 1.5 turns 0.9mm dia wire on Siemens A1 x 1 2 hole core

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